

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	3408505	memory or storage	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/15 13:29
L2	111435	1 and substrate and gate	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/15 13:30
L3	2164	2 and charg\$5 with side with gate	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/15 13:30
L4	45727	2 and channel and source and drain	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/15 13:31
L5	1674	3 and 4	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/15 13:31
L6	815	5 and current with source with drain	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/15 13:32
L7	743	6 and (voltage or potential or level) near5 source	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/15 13:33
L8	693	7 and (voltage or potential or level) near5 drain	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/15 13:33
L9	692	8 and (voltage or potential or level) near5 gate	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/15 13:34
L10	543	9 and p with substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/15 13:34
L11	432	10 and hole	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/15 13:35

## EAST Search History

L12	144	11 and single near3 gate	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/15 13:35
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